SEMICONDUCTOR

SS520LB

LOW VF SCHOTTKY BARRIER RECTIFIER

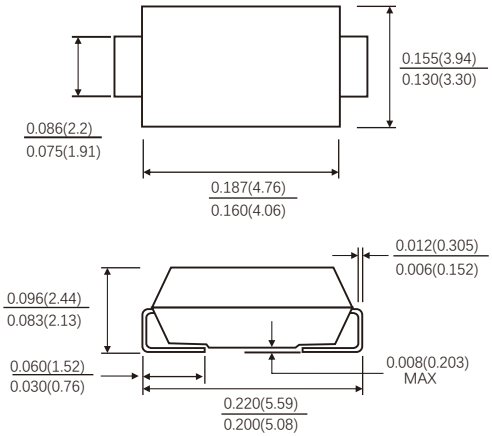
Reverse Voltage - 200 Volts
Forward Current - 5.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- High temperature soldering guaranteed:260℃/10 seconds at terminals
- Component in accordance to RoHS 2015/863/EU

Pb
RoHS
COMPLIANT

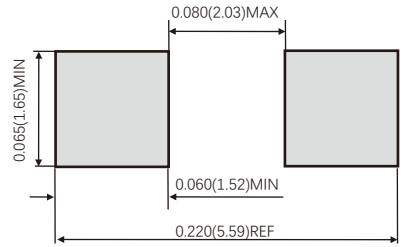
SMB(DO-214AA)



MECHANICAL DATA

Case: SMB(DO-214AA) molded plastic body
Terminals: Solder Plated, solderable per MIL-STD-750,method 2026
Polarity: Color band denotes cathode end

Suggested PAD Layout



Dimensions in inches and (millimetrers)

TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

MAXIMUM RATINGS

(Ratings at 25℃ ambient temperature unless otherwise specified)

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	200	V
Maximum average forward rectified current (see fig.1)	$I_{F(AV)}$	5.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	120	A
Operating junction temperature range	T_J	-55 to+150	℃
Storage temperature range	T_{stg}	-55 to+150	℃

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RATINGS AND CHARACTERISTICS OF SS520LB

ELECTRICAL CHARACTERISTCS（T_A=25℃ Unless otherwise noted）

Parameter	Test Conditions		Symbol	TYP.	MAX.	Unit
Instaneous forward voltage	I_F=5.0A	T_A=25℃	V_F 1)	0.81	0.90	V
		T_A=100℃		0.69	–	
		T_A=125℃		0.66	–	
	I_F=2.0A	T_A=25℃		0.74	–	
		T_A=100℃		0.63	–	
		T_A=125℃		0.59	–	
Reverse current	VR=200V	T_A=25℃	I_R 2)	5	20	μA
		T_A=100℃		–	1.0	mA
		T_A=125℃		–	3.0	
Typical junction capacitance	4V,1MHz		C_J	100		pF

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Pulse test: pulse width≤40ms

THERMAL CHARACTERISTCS

Parameter	Symbol	SMB	Unit
Typical thermal resistance 3)	$R_{\theta JA}$	70	℃/W
	$R_{\theta JL}$	15	

3.P.C.B. mounted with 0.118" x 0.118" (3.0 mm x 3.0 mm) copper pad areas （≥40μm thick)

AVAILABALE PACK INFORMATION

Product code	Pack	Reel Size (mm)	Quantity (pcs/reel)	Box Size L×W×H (mm)	Quantity (reel/box)	Carton Size L×W×H (mm)	Quantity (box/carton)
SS520LB-SMB	T/R	Φ300	3000	340×340×40	2	370×370×370	8

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RATINGS AND CHARACTERISTICS OF SS520LB

FIG.1-FORWARD CURRENT DERATING CURVE

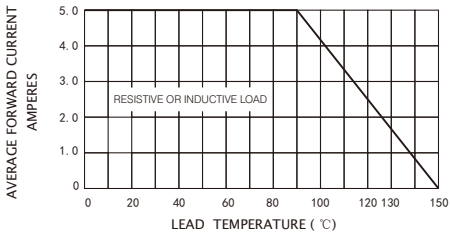


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

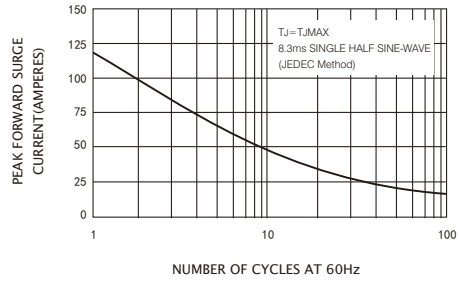


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

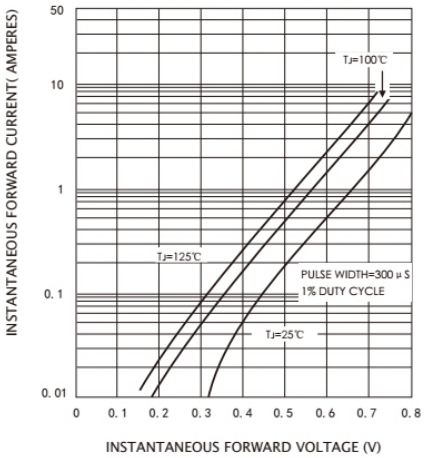
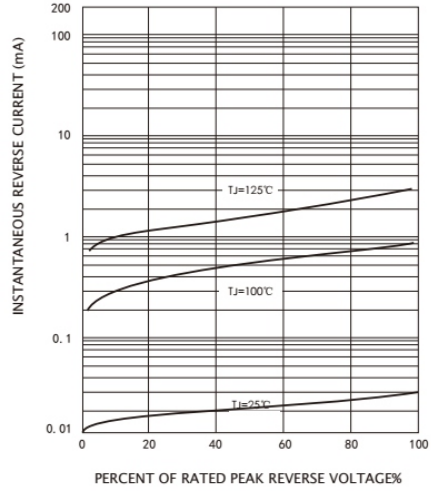


FIG.4-TYPICAL REVERSE CHARACTERISTICS



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